Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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MOS FIELD EFFECT TRANSISTOR



2SK2512

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK2512 is N-Channel MOS Field Effect Transistor designed for high current switching applications.

FEATURES

· Low On-Resistance

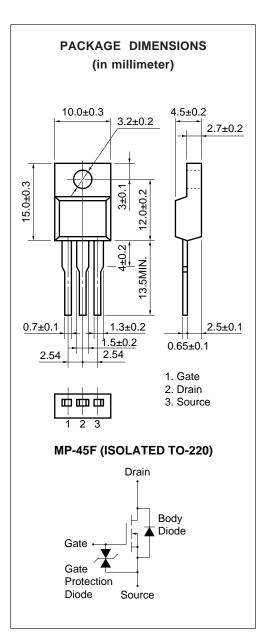
RDS (on)1 = 15 m Ω (VGS = 10 V, ID = 23 A) RDS (on)2 = 23 m Ω (VGS = 4 V, ID = 23 A)

- Low Ciss Ciss = 2 100 pF TYP.
- · Built-in G-S Protection Diode

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

Drain to Source Voltage	VDSS	60	V
Gate to Source Voltage	Vgss	±20	V
Drain Current (DC)	$I_{D(DC)}$	±45	Α
Drain Current (pulse)*	I _D (pulse)	±180	Α
Total Power Dissipation (Tc = 25 °C)	P _{T1}	35	W
Total Power Dissipation (T _A = 25 °C)	P_{T2}	2.0	W
Channel Temperature	T_ch	150	°C
Storage Temperature	T _{stg} -	–55 to +150) °C
* PW \leq 10 μ s, Duty Cycle \leq 1 %			

The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device is actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.



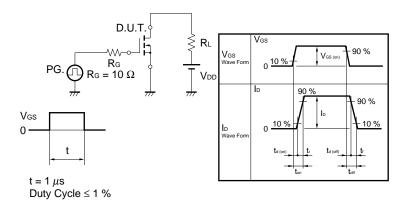




ELECTRICAL CHARACTERISTICS (TA = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	RDS (on)1		11	15	mΩ	Vgs = 10 V, ID = 23 A
Drain to Source On-Resistance	RDS (on)2		16	23	mΩ	Vgs = 4 V, ID = 23 A
Gate to Source Cutoff Voltage	VGS (off)	1.0	1.5	2.0	V	V _{DS} = 10 V, I _D = 1 mA
Forward Transfer Admittance	yfs	15	20		S	Vps = 10 V, Ip = 23 A
Drain Leakage Current	IDSS			10	μΑ	VDS = VDSS, VGS = 0
Gate to Source Leakage Current	Igss			±10	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Input Capacitance	Ciss		2 100		pF	Vps = 10 V
Output Capacitance	Coss		1 100		pF	Vgs = 0
Reverse Transfer Capacitance	Crss		500		pF	f = 1 MHz
Turn-On Delay Time	td (on)		45		ns	ID = 23 A
Rise Time	tr		380		ns	VGS (on) = 10 V
Turn-Off Delay Time	td (off)		320		ns	VDD = 30 V
Fall Time	tr		320		ns	R _G = 10 Ω
Total Gate Charge	QG		101		nC	ID = 45 A
Gate to Source Charge	Qgs		7		nC	VDD = 48 V
Gate to Drain Charge	Q _{GD}		40		nC	Vgs = 10 V
Body Diode Forward Voltage	VF (S-D)		1.0		V	IF = 45 A, VGS = 0
Reverse Recovery Time	trr		100		ns	IF = 45 A, VGS = 0
Reverse Recovery Charge	Qrr		180		nC	di/dt = 100 A/μs

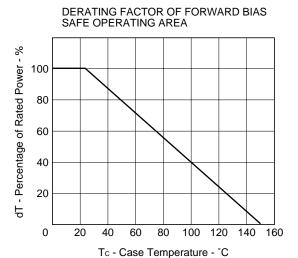
Test Circuit 1 Switching Time

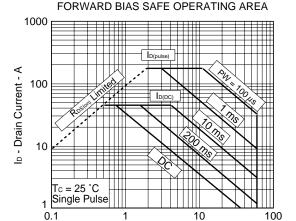


Test Circuit 2 Gate Charge

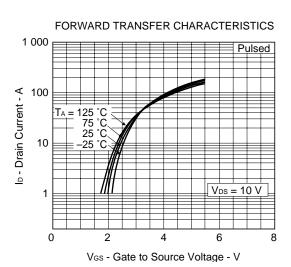
The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

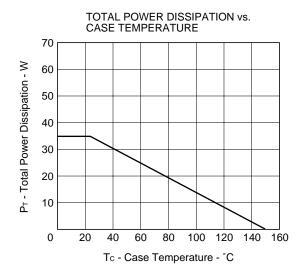
TYPICAL CHARACTERISTICS (TA = 25 °C)

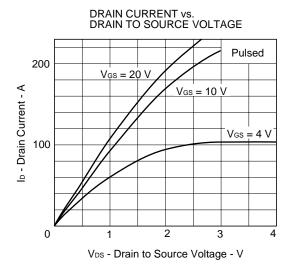




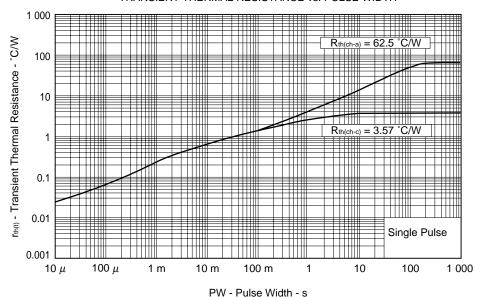
V_{DS} - Drain to Source Voltage - V



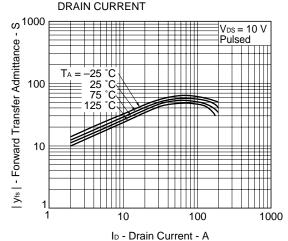


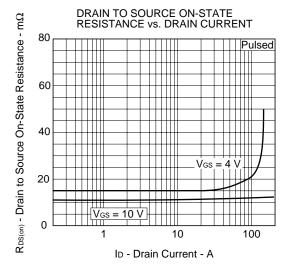


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

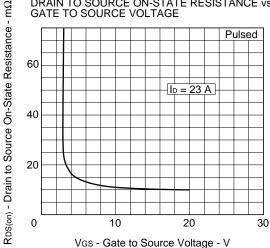


FORWARD TRANSFER ADMITTANCE vs.

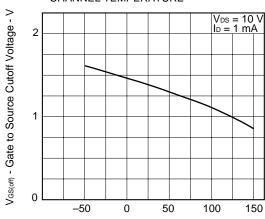


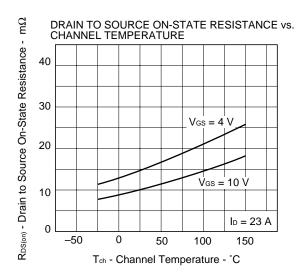


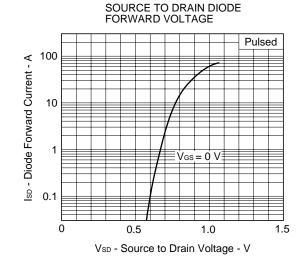
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

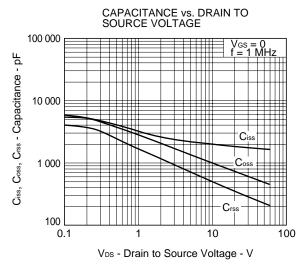


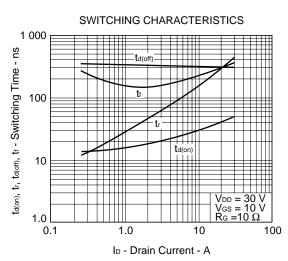
GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE

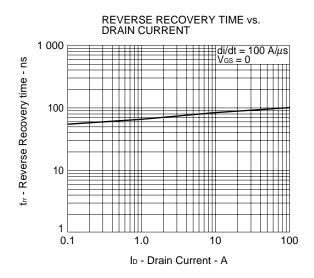


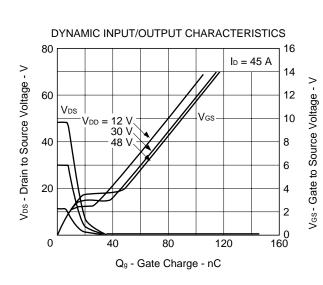
















REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037

[MEMO]



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Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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